

STTH1R02

Ultrafast recovery diode

Main product characteristics

I _{F(AV)}	1.5 A
V _{RRM}	200 V
T _j (max)	175° C
V _F (typ)	0.7 V
t _{rr} (typ)	15 ns

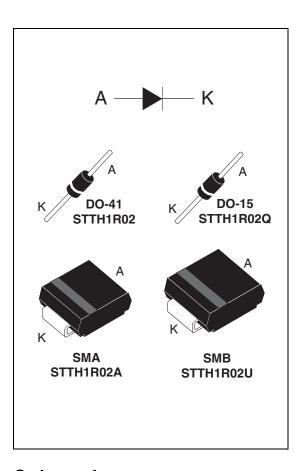
Features and benefits

- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery times
- High junction temperature

Description

The STTH1R02 uses ST's new 200 V planar Pt doping technology, and it is specially suited for switching mode base drive and transistor circuits.

Packaged in DO-41, DO-15, SMA, and SMB, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection.



Order codes

Part Number	Marking
STTH1R02	STTH1R02
STTH1R02RL	STTH1R02
STTH1R02A	R1A
STTH1R02Q	STTH1R02Q
STTH1R02QRL	STTH1R02Q
STTH1R02U	1R2S

March 2007 Rev 3 1/10

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1 Characteristics

Table 1. Absolute ratings (limiting values at $T_j = 25^{\circ}$ C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			200	V
I _{FRM}	Repetitive peak forward current	DO-41 ⁽¹⁾ DO-15 ⁽¹⁾ SMA / SM	t _p = 5 μs, F = 5 kHz	30	Α
I _{F(RMS)}	RMS forward current	DO-41 / DO-15 SMA /SMB		50	Α
I _{F(AV)}	Average forward current, $\delta = 0.5$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		1.5	Α
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms Sinusoidal}$			60	Α
T _{stg}	Storage temperature range			-65 to + 175	°C
T _j	Maximum operating junction temperature			175	°C

^{1.} On infinite heatsink with 10 mm lead length

Table 2. Thermal parameters

Symbol	Parameter			Value	Unit
D	Junction to lead		DO-41	45	
$R_{th(j-l)}$	Junction to lead	Lead Length = 10 mm on infinite heatsink	DO-15	45	°C/W
В	D. Jungtion to cook		SMA	30	C/VV
R _{th(j-c)} Junction to case			SMB	30	

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25° C	V _R = V _{RRM}			3	μΑ
		T _j = 125° C			2	20	
	V _F ⁽²⁾ Forward voltage drop	T _j = 25° C	I _F = 4.5 A			1.2	
V (2)		T _j = 25° C			0.89	1	V
V F.		T _j = 100° C	I _F = 1.5 A		0.76	0.85	V
		T _j = 150° C			0.70	0.80	

^{1.} Pulse test: t_p = 5 ms, δ < 2 %

To evaluate the conduction losses use the following equation: P = 0.68 x $I_{F(AV)}$ + 0.08 $I_{F}^{2}_{(RMS)}$

^{2.} Pulse test: t_p = 380 μ s, δ < 2 %

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Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур	Max.	Unit
		$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25^{\circ} \text{ C}$		23	30	ns
t _{rr} Reverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -100 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25^{\circ} \text{ C}$		15	20	115	
I _{RM}	Reverse recovery current	$I_F = 1.5 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s},$ $V_R = 160 \text{ V}, T_j = 125^{\circ} \text{ C}$		3	4	Α
t _{fr}	Forward recovery time	$I_F = 1.5 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, T_j = 25^{\circ} \text{ C}$		50		ns
V _{FP}	Forward recovery voltage	$I_F = 1.5 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s},$ $T_j = 25^{\circ} \text{ C}$		2.1		V

Figure 1. Peak current versus duty cycle

Figure 2. Forward voltage drop versus forward current (typical values)

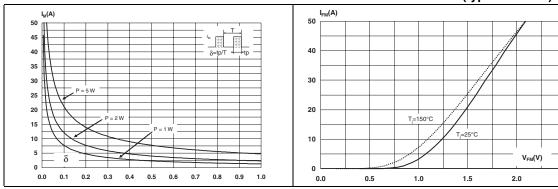
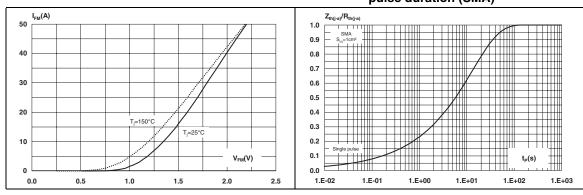


Figure 3. Forward voltage drop versus forward current (maximum values)

Figure 4. Relative variation of thermal impedance junction to case versus pulse duration (SMA)



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2.5

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Figure 5. Relative variation of thermal impedance junction to case versus pulse duration (SMB)

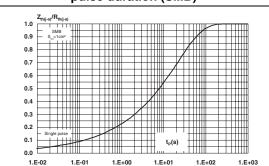


Figure 6. Relative variation of thermal impedance junction to case versus pulse duration (DO-41)

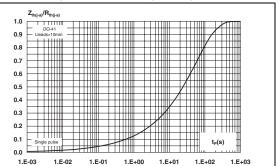


Figure 7. Relative variation of thermal impedance junction to case versus pulse duration (DO-15)

Figure 8. Junction capacitance versus reverse applied voltage (typical values)

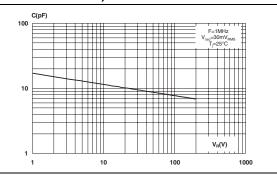


Figure 9. Reverse recovery charges versus dl_F/dt (typical values)

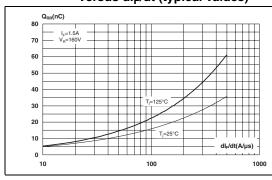
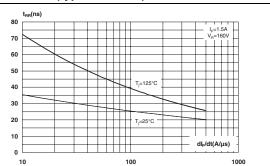


Figure 10. Reverse recovery time versus dI_F/dt (typical values)



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Figure 11. Peak reverse recovery curent versus dl_F/dt (typical values)

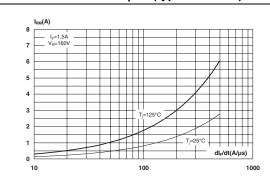


Figure 12. Dynamic parameters versus junction temperature

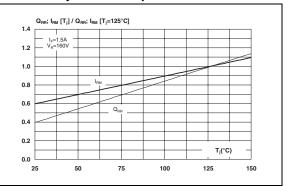


Figure 13. Thermal resistance, junction to ambient, versus copper surface under each lead - SMA (Epoxy FR4, copper thickness = $35 \mu m$)

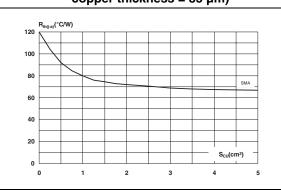


Figure 14. Thermal resistance, junction to ambient, versus copper surface under each lead - SMB (Epoxy FR4, copper thickness = 35 μm)

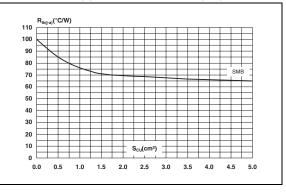


Figure 15. Thermal resistance, junction to ambient, versus copper surface under each lead - DO 15 (Epoxy FR4, copper thickness = 35 µm)

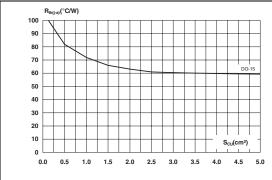
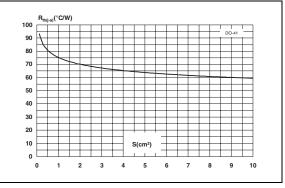
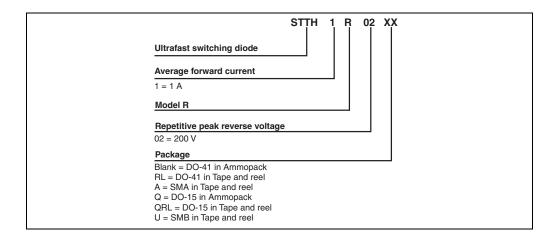


Figure 16. Thermal resistance, junction to ambient, versus copper surface under each lead - DO-41 (Epoxy FR4, copper thickness = 35 μm)



2 Ordering information scheme



3 Package information

Epoxy meets UL94, V0

Table 5. DO-41 dimensions

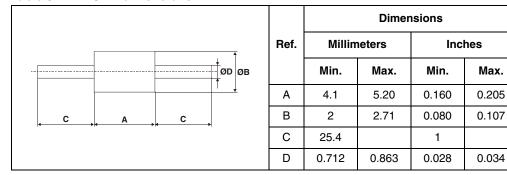
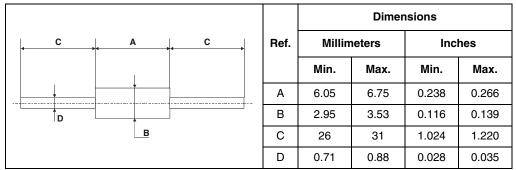


Table 6. DO-15 dimensions



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STTH1R02 **Package information**

Inches

Max.

0.080

0.008

0.065

0.016

0.220

0.181

0.116

0.063

Min.

0.075

0.002

0.049

0.006

0.189

0.156

0.089

0.030

Table 7. **SMA dimensions**

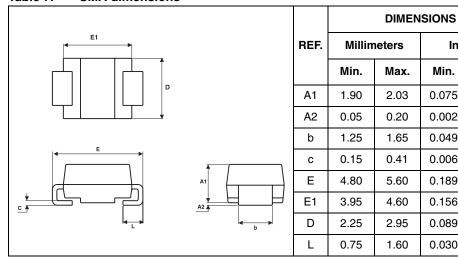
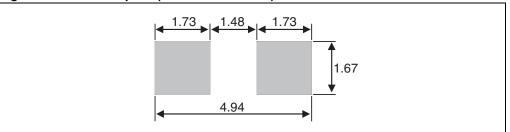
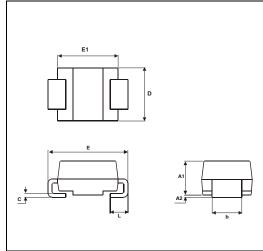


Figure 17. SMA footprint (dimensions in mm)



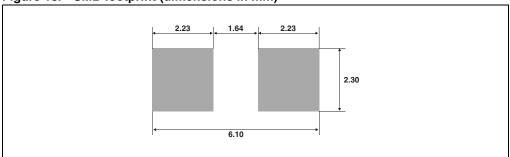
Package information STTH1R02

Table 8. SMB dimensions



	Dimensions				
Ref.	Millim	neters	Inc	hes	
	Min.	Max.	Min.	Max.	
A1	1.90	2.45	0.075	0.096	
A2	0.05	0.20	0.002	0.008	
b	1.95	2.20	0.077	0.087	
С	0.15	0.41	0.006	0.016	
Е	5.10	5.60	0.201	0.220	
E1	4.05	4.60	0.159	0.181	
D	3.30	3.95	0.130	0.156	
L	0.75	1.60	0.030	0.063	

Figure 18. SMB footprint (dimensions in mm)



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

4 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH1R02	STTH1R02	DO-41	0.34 g	2000	Ammopack
STTH1R02RL	STTH1R02	DO-41	0.34 g	5000	Tape and reel
STTH1R02A	R1A	SMA	0.068 g	5000	Tape and reel
STTH1R02Q	STTH1R02Q	DO-15	0.49 g	1000	Ammopack
STTH1R02QRL	STTH1R02Q	DO-15	0.49 g	6000	Tape and reel
STTH1R02U	1R2S	SMB	0.11 g	2500	Tape and reel

5 Revision history

Date	Revision	Description of changes
03-May-2006	1	First issue
13-Oct-2006	2	Added DO-15 and SMB packages.
08-Mar-2007	3	Replaced Figure 8. Replaced e _{cu} with copper thickness.

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